# **Chemical Science**

## EDGE ARTICLE



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### Introduction

Organic light-emitting diodes (OLEDs) have achieved largescale commercial applications in full-color displays and solidstate lighting due to their unique advantages.<sup>1-6</sup> However, compared to red, green, and blue (RGB) OLEDs,<sup>5,7-10</sup> the development of near-ultraviolet (NUV) OLEDs with a Commission Internationale de l'Eclairage y coordinate (CIEy) below 0.035 is dropping noticeably behind. It's known that NUV emitters have

# A record-high EQE of 7.65%@3300 cd m−<sup>2</sup> achieved in non-doped near-ultraviolet OLEDs based on novel D'-D-A type bipolar fluorophores upon molecular configuration engineering†

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Developing a high-performance near-ultraviolet (NUV) material and its simple non-doped device with a small efficiency roll-off and good color purity is a promising but challenging task. Here, we proposed a novel donor'-donor-acceptor (D'-D-A) type molecular strategy to largely solve the intrinsic contradictions among wide-bandgap NUV emission, fluorescence efficiency, carrier injection and transport. An efficient NUV fluorophore, 3,6-mPPICNC3, exhibiting a hybridized local and chargetransfer state, is achieved through precise molecular configuration engineering, realizing similar hole and electron mobilities at both low and high electric fields. Moreover, the planarized intramolecular charge transfer excited state and steric hindrance effect endow 3,6-mPPICNC3 with a considerable luminous efficiency and good color purity in the aggregation state. Consequently, the non-doped device emitting stable NUV light with Commission Internationale de l'Eclairage (CIE) coordinates of (0.160, 0.032) and a narrow full width at half maximum of 44 nm exhibits a state-of-the-art external quantum efficiency (EQE) of 7.67% and negligible efficiency roll-off over a luminance range from 0 to 3300 cd m<sup>-2</sup>. This is a record-high efficiency among all the reported non-doped NUV devices. Amazingly, an EQE of 7.85% and CIE coordinates of  $(0.161, 0.025)$  are achieved in the doped device. This demonstrates that the D'-D–A-type molecular structure has great potential for developing high-performance organic lightemitting materials and their optoelectronic applications. EDGE ARTICLE<br> **A** record-high EQE of 7.65%@3300 cd m<sup>-2</sup> achieve<br> **a** chest for unders and in non-doped near-ultraviolet OLEDs based on<br>
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broad application space and development prospects in the fields of optoelectronics, excitation light sources, high-density information storage, biological and medical applications. $11,12$ Although some efforts have been made via rational molecular design or device engineering, external quantum efficiencies (EQEs) usually lie below 7% in simple non-doped NUV-OLEDs.3,13–<sup>28</sup> Moreover, most of the NUV-OLEDs suffer from serious efficiency roll-off at a high luminance level and poor color purity (the full width at half maximum (FWHM) value exceeding 50 nm), due to the intermolecular aggregation, strong intramolecular charge transfer (CT) effect, and unbalanced carrier injection, transport, and recombination.

For pursuing an efficient NUV material and its non-doped device, there are several aspects that need to be taken into thorough consideration during molecular design. First, the emitter should possess suitable molecular rigidity and an adequate molecular weight to ensure excellent thermal and morphological stabilities, thereby mitigating the impact of Joule heating on device degradation. Second, the molecular conjugation length and intermolecular aggregation effect must be carefully controlled to strike a balance between the NUV emission and photoluminescence (PL) efficiency. Additionally, the efficient utilization of electro-

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#### Chemical Science **Edge Article**

generated excitons is a crucial factor that affects the electroluminescence (EL) performance of NUV-OLEDs. Thermally activated delayed fluorescence (TADF) and noble-metal phosphorescent emitters can harvest both singlet and triplet excitons, achieving 100% exciton utilization efficiency (EUE).<sup>1,29</sup> However, it is virtually impossible to efficiently realize non-doped TADF or phosphorescent NUV-OLEDs with low efficiency roll-off due to the long exciton lifetimes and the principles of meticulous molecular design. A more prospective strategy is to construct NUV fluorophores with a hybridized local and charge-transfer (HLCT) excited state, which involves a high-lying reverse intersystem crossing (RISC) process that converts high-energy triplet excitons into singlet excitons, thereby facilitating the reutilization of triplet excitons. The efficient segregation of exciton conversion and radiation transition channels, coupled with the moderate strengths of donor/acceptor units, bestows HLCT emitters with both remarkable luminous efficiency and exceptional NUV emission capabilities.<sup>30</sup> Recently, most efficient HLCT-type NUV-OLEDs have been reported. For example, Li et al. realized a record-high maximum EQE of 11.3% and a high color purity EL peaking at 394 nm based on a doped emissive layer with an 8 wt% BO-biphenyl emitter.<sup>31</sup> Gan et al. reported a maximum EQE of 9.15% with the EL peak at 414 nm and a CIEy of 0.034 in the doped device with a doping concentration of 5 wt%.<sup>26</sup> Zhang et al. and Chen et al. realized maximum EQEs of 10.79% and 8.2% with CIE coordinates of (0.161, 0.031) and (0.161, 0.034) for carbazole-based emitters (2BuCzCNCz and POPCN-2CP) in the doped devices, while the EQEs were down to 5.24% and 7.5% with large FWHMs of 62 and 52 nm in the non-doped OLEDs.32,33 Although the host–guest doping strategy can mitigate spectral redshift and enhance PL efficiency to a certain extent, such doped devices often face challenges such as potential phase separation issues, elevated processing costs, and the difficulty in selecting appropriate host materials. In previous work, we reported an efficient HLCT emitter (mP2MPC) via the meta-linkage pattern, achieving a maximum EQE of 6.09% with CIE coordinates of  $(0.163, 0.028)$  and a FWHM of 51 nm in the non-doped device.<sup>34</sup> Han et al. reported an emitter TPBCzC1 with a maximum EQE of 4.4% and a CIEy value of 0.035 in the non-doped OLED.<sup>35</sup> Until now, a record-breaking EQE of 7.5% with CIE coordinates (0.159, 0.035) and a FWHM of 52 nm has been achieved.<sup>33</sup> However, spectral broadening and the imbalance in hole/electron injection, transport, and recombination render non-doped NUV-OLEDs vulnerable to significant efficiency roll-off and compromised color purity.13,36,37 Therefore, it is highly desirable and imperative to pursue a credible molecular design strategy that effectively addresses the aforementioned contradictions, thereby further promoting the advancement of non-doped NUV-OLEDs and their application at high luminance levels. Chemical Science<br>
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In this work, we proposed a feasible donor'–donor–acceptor  $(D'-D-A)$  type molecular design strategy to construct highefficiency bipolar HLCT molecules with wide-bandgap emission. The above contradictions can be well reconciled by engineering molecular configuration precisely. As a result, the material 4-(6-(3-(1-phenyl-1H-phenanthro[9,10-d]imidazol-2-yl) phenyl)-9-propyl-9H-carbazol-3-yl)benzonitrile (3,6-mPPICNC3) exhibits remarkable fluorescence efficiencies in dispersion and aggregation states, as well as well-balanced hole and electron

mobilities at both low and high electric fields. The non-doped OLED based on 3,6-mPPICNC3, exhibiting a small CIEy value of 0.032, achieves a maximum EQE of 7.67%. Remarkably, it maintains a significant value of 7.65% at 3300 cd  $\mathrm{m}^{-2}$ , showing negligible efficiency roll-off. This represents the state-of-the-art efficiency for non-doped NUV-OLEDs, particularly considering its CIEy value and minimal efficiency roll-off at such a high luminance level.

### Results and discussion

#### Molecular design strategy and synthesis

A donor–acceptor (D–A) type emitter is a universal molecular paradigm to alleviate the problem of carrier injection and  $transport$ , $27,38-40$  which can effectively broaden the exciton recombination zone, and further suppress exciton quenching. Additionally, it has been proven that a D–A type emitter with the intramolecular CT effect can enhance the utilization of triplet excitons by the RISC process, such as the TADF and HLCT mechanism. However, the strong intramolecular CT effect would also trigger phenomena such as bathochromic shift of emission, inferior color purity and reduced overlap of molecular frontier orbitals (resulting in low fluorescence efficiency) to a certain extent. Several successful strategies have been proposed to weaken this effect for exploiting D–A-type NUV emitters, for example, incorporating a steric group, introducing a twisted bridge, and utilizing weak electron-donating/ accepting groups. Based on these strategies, a series of  $D-(\pi)$ – A type,<sup>41</sup> donor-acceptor-donor (D-A-D) type,<sup>42-45</sup> acceptordonor-acceptor (A-D-A) type,<sup>46</sup> and donor'-acceptor-donor (D'-A–D) type wide-bandgap organic emitters were reported in doped OLEDs (Fig. 1).<sup>47</sup> Nevertheless, non-doped NUV-OLEDs still display unsatisfactory EL performance. Here, we proclaim a promising and novel D′–D–A-type molecular design strategy to address the abovementioned contradictions, where N-propylmodified carbazole (C3Cz) with the exceptional merits of hole transport ability and good thermal stability was selected as a rigid bridged donor;<sup>48-52</sup> benzonitrile (PhCN) was selected as an acceptor that may enhance supramolecular interactions in the neat film;<sup>53-56</sup> a 1,2-diphenyl-1H-phenanthro[9,10-d]imidazole (PPI) chromophore with a low  $T_1$  energy level, good thermal stability and high fluorescent efficiency was selected as a second donor group,<sup>57</sup>–<sup>60</sup> which is linked to the C3Cz donor through a single bond. Such D'-D-A type molecular geometry endows the emitters with planarized intramolecular charge transfer (PLICT) state characteristics, maintaining high photoluminescence quantum yields (PLQYs) in dispersion and aggregation states.<sup>61,62</sup> Meanwhile, efficient NUV emission as well as balanced bipolar transport are achieved by precisely modulating molecular configuration engineering, that is regulating substitution modes onto C3Cz (3, 6 or 2, 7) and the substitution positions of PPI (meta- or para-position).

Accordingly, four isomers, namely 4-(7-(3-(1-phenyl-1H-phenanthro[9,10-d]imidazol-2-yl)phenyl)-9-propyl-9H-carbazol-2-yl) benzonitrile (2,7-mPPICNC3) and 4-(7-(4-(1-phenyl-1H-phenanthro[9,10-d]imidazol-2-yl)phenyl)-9-propyl-9H-carbazol-2-yl) benzonitrile (2,7-pPPICNC3), 4-(6-(4-(1-phenyl-1H-phenanthro



#### [9,10-d]imidazol-2-yl)phenyl)-9-propyl-9H-carbazol-3-yl)

benzonitrile (3,6-pPPICNC3), and 3,6-mPPICNC3 were designed and facilely synthesized (Schemes S1–S3†). The detailed synthesis method and structural characterization are described in the ESI.† According to the thermogravimetric analysis and differential scanning calorimetry measurements (Fig. S1†), high decomposition temperatures  $(T<sub>d</sub>, 5\%$  weight loss) of 439, 495, 492, and 459 °C are achieved for 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3, and 2,7-pPPICNC3, respectively. The glass transition temperature  $(T_g)$  was determined to be 143 °C for 2,7**mPPICNC3**, while no  $T_g$ s were observed for other emitters in the temperature range of 25-300  $\mathrm{^{\circ}C}$  (Fig. S2†). In addition, the surface morphology and PL spectrum of the vacuum-sublimed film were almost unchanged after exposed to the ultraviolet lamp for 24 h (Fig. S3†). These results indicate that all the isomers have excellent thermostability and photostability, which is desired for improving the efficiency and lifetime of OLEDs. As shown in Fig. S4,† the oxidation potentials were determined to be 0.896, 0.853, 0.896 and 0.867 V, referring to the highest occupied molecular orbital (HOMO) energy levels of −5.20, −5.17, −5.16 and −5.18 eV for 3,6-mPPICNC3, 3,6 pPPICNC3, 2,7-mPPICNC3, and 2,7-pPPICNC3. Lowest unoccupied molecular orbital (LUMO) energy levels can be calculated to be  $-1.87, -2.01, -1.90$  and  $-2.12$  eV, according to the differences between HOMOs and optical bandgaps  $(E_{\rm g}s)$ .

#### Theoretical calculations

The optimization of geometrical configurations, frontier molecular orbital (FMO) distributions of 3,6-mPPICNC3, 3,6-

pPPICNC3, 2,7-mPPICNC3, and 2,7-pPPICNC3, and their building units was performed by density functional theory (DFT) calculations at the B3LYP/6-31G(d,p) basis set. As shown in Fig. S5,† there exist limited HOMO distributions on the C2 and C7 atoms of the C3Cz unit and meta-position C atom of the PPI group, signifying that the conjugation interaction among building units can be well controlled by the molecular configuration engineering. It can be seen in Fig. 2 that all the emitters show moderately distorted molecular conformation with D–A dihedral angles ( $\theta_1$ s) of 35.99–36.43°, twist angles ( $\theta_2$ s) of 33.36– 36.30° between C3Cz and the connected benzene of the PPI unit, and twist angles  $(\theta_3 s)$  of 19.71–30.02° between imidazole and connected benzene. The HOMO distributions are mainly limited to the additional donor PPI for 3,6-mPPICNC3 and 2,7 mPPICNC3, while they are further slightly extended to the adjacent C3Cz group in the molecules 3,6-pPPICNC3 and 2,7 pPPICNC3. The LUMOs of 3,6-mPPICNC3 and 3,6-pPPICNC3 were mostly distributed on the PhCN segment with minor contribution from the donor-bridge C3Cz, while those are exclusively located on the whole PhCN and central carbazole and a residual on the adjacent benzene ring in the case of 2,7 mPPICNC3 and 2,7-pPPICNC3. Consequently, 3,6-mPPICNC3 and 2,7-pPPICNC3 show the widest and least energy gaps of 3.62 and 3.40 eV, respectively.

In order to investigate the excited state properties of all the emitters, the optimization of the geometry of the lowest singlet  $(S_1)$  excited state and natural transition orbital (NTO) analysis were carried out. The variations of geometric conguration between the ground  $(S_0)$  state and  $S_1$  state are shown in Fig. 2. The dihedral angles  $(\theta_1, \theta_2, \text{ and } \theta_3)$  in the S<sub>1</sub> state



Fig. 2 Chemical structures, optimized geometry configurations of ground states and singlet states and FMO distributions for (a) 3,6-mPPICNC3, (b) 3,6-pPPICNC3, (c) 2,7-mPPICNC3, and (d) 2,7-pPPICNC3.

become smaller, which decrease from 36.43°, 34.11° and 30.02° to 29.11°, 26.91° and 25.16° for 3,6-mPPICNC3, from 35.99°, 36.30° and 27.80° to 22.07°, 21.36° and 7.75° for 3,6 pPPICNC3, from 36.39°, 33.36° and 19.71° to 28.21°, 17.45 and 13.31° for 2,7-mPPICNC3, and from 36.29°, 35.71° and 24.56° to 21.97°, 20.50° and 7.51° for 2,7-pPPICNC3, respectively. Such a phenomenon demonstrates that all the emitters possess the PLICT features in the excited state exactly.45,61,63,64 In addition, as shown in Table S1,† the bond lengths  $(L_1, L_2)$ and  $L_3$ ) between C3Cz and PhCN (PPI) units are shortened from  $S_0$  to  $S_1$  geometries for all the emitters. Taking 3,6mPPICNC3 as an example,  $L_1$ ,  $L_2$  and  $L_3$  are calculated as 1.477, 1.481 and 1.467 Å for the  $S_0$  geometry, which reduce to 1.455, 1.476 and 1.450 Å in the  $S_1$  geometry. This result provides a new proof for the existence of the PLICT process. As shown in Tables S2–S5,† there are some scale of orbital overlap on the carbazole group for 3,6-mPPICNC3 and on the benzene ring of the PPI unit for 2,7-mPPICNC3 in the  $S_0 \rightarrow S_1$  transition, while a large orbital separation exists between hole and particle distributions, belonging to CT-dominated HLCT excited states. In the  $S_0 \rightarrow S_2$  transition, 3,6-mPPICNC3 and 2,7mPPICNC3 show archetypal HLCT excited states with the hole and particle undergoing partial separation and partial overlap. The  $S_0 \rightarrow S_1$  transitions for 3,6-pPPICNC3 and 2,7-pPPICNC3 with the para-substitution of the PPI group can be considered as typical HLCT states, where the hole and particle distributions show large overlaps in the carbazole and benzene component of PPI, and effective separation in the second

donor and acceptor segments. This endows them with higher oscillator strengths than that of the isomers with metasubstitution of the PPI group. As shown in Tables S6 and S7,† the calculated  $S_1$  and  $T_1$  energy levels are 3.343 and 2.710 eV for 3,6-mPPICNC3, 3.285 and 2.606 eV for 3,6-pPPICNC3, 3.343 and 2.626 eV for 2,7-mPPICNC3, and 3.107 and 2.506 eV for 2,7-pPPICNC3, respectively, corresponding to the energy splittings ( $\Delta E_{\rm ST}$ s) between S<sub>1</sub> and T<sub>1</sub> of 0.633, 0.679, 0.717 and 0.601 eV, excluding the TADF process. As for 3,6-mPPICNC3, the high-lying triplet states  $(T_4, T_5, T_6)$  show obvious HLCT, locally excited (LE) and HLCT states, which show smaller energy differences (0.0173, 0.115 and 0.004 eV) and larger spin–orbit coupling (SOC) values (0.147, 0.128 and 0.059  $\text{cm}^{-1}$ ) with the S<sub>1</sub> state. This revelation indicates that it could facilitate multi-channel high-lying RISC processes, according to Fermi's golden and El-Sayed rules (Fig. S6†).<sup>65,66</sup> Correlation analysis of other isomers is shown in the ESI.†

#### Photophysical properties

The absorption and PL spectra of 3,6-mPPICNC3, 3,6 pPPICNC3, 2,7-mPPICNC3 and 2,7-pPPICNC3 in dilute toluene solution are illustrated in Fig. 3a. The absorption peaks at around 285 and 305 nm can be attributed to the absorption of the carbazole unit, while the absorption band in the range of 325–365 nm may be ascribed to the  $\pi-\pi^*$  transition of the PPI unit.<sup>67</sup> It is worth noting that low-energy bands were observed at different positions for the isomers, resulting from varying



Fig. 3 (a) Normalized absorption and PL spectra of 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3 and 2,7-pPPICNC3 in toluene solution (10−<sup>5</sup> M). (b) Normalized PL spectra in the neat film. (c) PLQYs in toluene and the neat film. (d) Transient PL decay spectra in the neat film.

degrees of  $\pi$ -conjugation expansion, which is highly dependent on the positions of attachment of A and  $D'$  units to the C3Cz donor. According to the onset of absorption spectra, the values of  $E_g$  can be estimated to be 3.33, 3.16, 3.26 and 3.06 eV for 3,6mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3 and 2,7-pPPICNC3, respectively. It can be seen from PL spectra that all the compounds are emitted in the NUV to deep-blue light region with the maximum peaks of 389, 400, 424 and 417 nm, corresponding to PL quantum yields (PLQYs) of 82.6%, 95.2%, 93.3% and 97.5%, respectively (Fig. 3c). Moreover, the PL spectra of 3,6-mPPICNC3 and 2,7-mPPICNC3 with the meta-linkage of PPI exhibit structureless profiles, while those of 3,6-pPPICNC3 and 2,7-pPPICNC3 with the para-linkage of PPI feature distinct vibronic fine structures. The PL peaks of the neat films exhibit a certain degree of bathochromic-shifts at 419, 437, 443 and 460 nm with the related FWHMs of 45, 50, 51 and 55 nm, corresponding to the PLQYs of 59.1%, 63.0%, 61.9% and 63.3% for 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3 and 2,7 pPPICNC3, respectively (Fig. 3b and c). Notably, such high PLQY values achieved in neat films are higher than those of most reported HLCT emitters.58,68–<sup>72</sup> By comparison with other isomers, 3,6-mPPICNC3 exhibits a blue-shift with higher color purity, which can be attributed to the rigid configuration and large steric hindrance effect that can effectively suppress the structure relaxation and intermolecular aggregation. The doped

film with a 5 wt% emitter dispersed into polar poly(methyl methacrylate) (PMMA) exhibits blue-shifted PL peaks of 399, 425, 422 and 443 nm, with the enhanced PLQYs of 61.4%, 93.4%, 91.0% and 97.4% (Fig. S7†). Table 1 summarizes the photophysical and electrochemical parameters of the four isomers.

Low-temperature fluorescence and phosphorescence spectra at 77 K in toluene solution were measured to estimate the  $S_1$  and  $T_1$  energy levels (Fig. S8†). According to the emission peaks, the  $\Delta E_{\rm ST}$ s can be calculated to be 0.63, 0.67, 0.56, and 0.54 eV for 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3 and 2,7 pPPICNC3, respectively (Table 1). Moreover, transient PL decay curves in solutions and films show single-exponential fluorescence lifetimes in the nanosecond range (Fig. 3d, S9, S10 and Table S8†), which further illustrates that the TADF process can be ruled out. Due to the rapid RISC process from high-lying triplet states to  $S_1$ , the delayed lifetimes and RISC rates cannot be obtained.<sup>30</sup> Based on the PLQYs and decay lifetimes, the radiative and non-radiative rates  $(k_r$  and  $k_{nr}$ ) were calculated (Table S8†). All four emitters show outstanding  $k_r$  values exceeding  $1.9 \times 10^8$  s<sup>-1</sup>, which would inhibit the exciton annihilation effects and ameliorate the efficiency roll-off in the OLEDs. The emitters with *para*-connection between the  $D'$  and D units show higher  $k_r s$  as a result of the increased FMO overlaps. Specifically, the PLQYs were improved with the increase of

Table 1 The photophysical and electrochemical parameters of the emitters



<sup>a</sup> Measured in toluene solution (10<sup>-5</sup> M) at 300 K. <sup>b</sup> Measured in non-doped films at 300 K. <sup>c</sup> HOMO energy level: obtained from CV measurement.  $E_{\rm g}$ : calculated from the absorption onset in toluene solution. LUMO energy level: calculated by  $E_{\rm LUMO} = E_{\rm HOMO} + E_{\rm g}$ . Estimated by the peaks of lowtemperature fluorescence and phosphorescence spectra at 77 K,  $\Delta E_{ST} = E_{S_1} - E_{T_1}$ .

solvent polarity (Table S9†), which is consistent with the PLICT process.<sup>22,63</sup>

To further investigate the excited state properties, solvatochromic effects were measured in various solvents. It is found that the absorption spectra show nearly no changes with increasing solvent polarity (Fig. S11†), while their PL spectra exhibit significant redshifts as the solvent polarity increases (Fig. 4 and  $S12-S14\dagger$ ). All the emitters display clear vibronic fine structures in the low polar n-hexane solvent. As the solvent polarity increases, the emitters 3,6-mPPICNC3 and 2,7 mPPICNC3 gradually exhibit structureless and broadened PL emission, corresponding to a larger red-shift of 65 and 23 nm. In contrast, the PL spectra of 3,6-pPPICNC3 and 2,7-pPPICNC3 in the highly polar acetonitrile solvent display weak vibrational fine structure, illustrating that their  $S_1$  states hold more LE component than those of 3,6-mPPICNC3 and 2,7-mPPICNC3, agreeing well with the theoretical calculations. As was investigated through the analysis of Stokes shift versus solvent orientation polarizability curves by the Lippert–Mataga solvatochromic model, the two-segment linear relationship can be observed for 3,6-mPPICNC3 and 2,7-pPPICNC3, representing typical HLCT states.<sup>3,30</sup> 3,6-pPPICNC3 and 2,7-mPPICNC3 display linear relationships with excited state dipole moments of 10.45 and 11.47 debye, signifying that there exists only one excited state in different polar solvents, belonging to the quasi-Chemical Science<br>
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equivalent HLCT states.<sup>54,70,73</sup> This also was supported by the single-component nanosecond-scale fluorescence lifetimes and high PLQYs in both low and high polar solvents. These results indicate that all the emitters could achieve the reutilization of inactivated triplet excitons and enable the realization of highefficiency non-doped OLEDs.

#### Bipolar transport properties

The bipolar transport ability is one of the key factors contributing to efficiency roll-off in non-doped OLEDs. In order to evaluate it, single-carrier devices were fabricated with the configurations of [indium-tin-oxide  $(ITO)/1,3,5-tris(1-phenyl-$ 1H-benzo[d]imidazol-2-yl)benzene (TPBi, 10 nm)/emitters (80 nm)/TPBi (10 nm)/LiF (1 nm)/Al (100 nm)] for the electron-only devices (EODs) and  $[TTO/N^4,N^{4'}-di(naphthalen-1-yl)-N^4,N^{4'}-i(naphthalen-1-yl)]$ diphenyl-[1,1'-biphenyl]-4,4'-diamine (NPB, 10 nm)/emitters (80 nm)/NPB (10 nm)/Al (100 nm)] for hole-only devices (HODs). According to the space-limited-current (SCLC) method, which can be described by the Mott–Gurney eqn  $(1)$ :<sup>74</sup>

$$
J = \frac{9}{8} \varepsilon_0 \varepsilon_r \mu \frac{E^2}{L} \tag{1}
$$

Here,  $J$  is the current density,  $\varepsilon_0$  represents the vacuum permittivity ( $\varepsilon_0 = 8.85 \times 10^{-14} \text{ C V}^{-1} \text{ cm}^{-1}$ ),  $\varepsilon_r$  stands for the relative dialectric constant which is considered to be 2.0 for the relative dielectric constant, which is considered to be 3.0 for the



Fig. 4 Solvation effects on PL spectra (a) and Lippert–Mataga plots (b) for 3,6-mPPICNC3.

organic semiconductor,  $\mu$  represents the carrier mobility,  $E$  is the electric field intensity, and  $L$  means the thickness of the emitters. In view of the effect of energetic disorder on carrier mobility, the mobility dependent on the electric field can be expressed by a Poole–Frenkel equation:

$$
\mu = \mu_0 e^{-\gamma \sqrt{E}} \tag{2}
$$

Here,  $\mu_0$  is the zero-field mobility and  $\gamma$  is the Poole–Frenkel factor. Thus, the field-dependent SCLC can be expressed as:

$$
J = \frac{9}{8} \varepsilon_0 \varepsilon_\mathrm{r} \mu_0 \frac{V^2}{L^3} \mathbf{e}^{0.891\gamma} \sqrt{\frac{V}{L}}
$$
 (3)

It can be seen in Fig. S15† that the HODs and EODs produce significant hole or electron currents as the applied voltages increase, indicating that all the isomers exhibit a considerable bipolar transport nature. As shown in Fig. 5, substitution positions of the PPI unit have a slight effect on the electron mobility whereas the hole mobilities of para-isomers are superior to those of *meta*-isomers. In addition, compared to the 3,6-substitution mode on C3Cz, the 2,7-substitution mode decreases the hole mobility of emitters but enhances the electron mobility, attributed to deeper HOMO energy levels

and more planarized molecule structures. Consequently, the electron mobility decreases in the order 2.7-pPPICNC3 (2.83  $\times$  $10^{-5}$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>) > 2,7-mPPICNC3 (2.23 ×  $10^{-5}$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>) > 3,6-pPPICNC3  $(2.97 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1})$  > 3,6-mPPICNC3  $(1.52\times 10^{-6}$   ${\rm cm^2\,V^{-1}\,s^{-1}})$  at an electric field of  $5\times 10^5$  V  ${\rm cm^{-1}},$ while the hole mobility decreases in the order 3,6-pPPICNC3  $(4.26 \times 10^{-5} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1})$  > 2,7-pPPICNC3  $(1.47 \times 10^{-5} \text{ cm}^2$  ${\rm V}^{-1} \ \ {\rm s}^{-1}) \ > \ {\rm 3,6\text{-}mPPICNC3} \ \ (2.28 \ \times \ 10^{-6} \ \ {\rm cm^2} \ \ {\rm V}^{-1} \ \ {\rm s}^{-1}) \ >$ 2,7-mPPICNC3  $(6.15 \times 10^{-7} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1})$ , respectively. It should be noted that 3,6-mPPICNC3 exhibits more balanced electron and hole mobilities in both low and high electric fields, which can effectively suppress the exciton-polaron quenching effect, thereby resulting in a low efficiency roll-off at high current densities.

#### EL performance

Considering their high PLQYs and excellent bipolar transport properties, we further investigated the EL performance of non-doped devices with the four emitters as pure emissive layers, utilizing the optimized device configurations of ITO/ 1,4,5,8,9,11-hexaazatriphenylenehexacarbonitrile (HATCN, 20 mm)/4,4'-(cyclohexane-1,1-diyl)bis(N,N-di-p-tolylaniline) (TAPC, 45 nm)/tris(4-(9H-carbazol-9-yl)phenyl)amine (TCTA)



Fig. 5 Hole and electron mobilities versus electric field curves for (a) 3,6-mPPICNC3, (b) 3,6-pPPICNC3, (c) 2,7-mPPICNC3 and (d) 2,7pPPICNC3.



Fig. 6 (a) Device structures and energy level diagrams of the devices N1–4. (b) Normalized EL spectra at different applied voltages of the devices N1 and N2. (c) Current density–voltage–luminance curves of the devices N1–4. (d) EQEs versus luminance curves of the devices N1–4.

(10 nm)/emissive layer (20 nm)/TPBi (10 nm)/LiF (1 nm)/Al (100 nm). Here, the emissive layers of devices (N1, N2, N3 and N4) correspond to 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7 mPPICNC3 and 2,7-pPPICNC3; HATCN, LiF, TAPC, TCTA, and TPBi served as hole-injection, electron-injection, holetransport, exciton-blocking, and electron-transport layers, respectively. The relevant organic molecular structures, energy level diagrams and EL performance of the devices are shown in Fig. 6 and S16–S18,† and the corresponding values are listed in Table 2. As expected, the device N1 with 3,6 mPPICNC3 as the pure emissive layer displays a stable NUV emission with good color purity, corresponding to the CIE coordinates of (0.162, 0.032) and the FWHM value of 44 nm (0.313 eV). Additionally, devices N2–4, based on 3,6 pPPICNC3, 2,7-mPPICNC3 and 2,7-pPPICNC3, respectively, show red-shifted and slightly broadening emissions located in deep-blue and blue light regions, having CIE coordinates of (0.154, 0.057), (0.155, 0.075), and (0.158, 0.141), respectively. Notably, devices N1–4 exhibit low turn-on voltages ranging from 2.7 to 2.9 V due to the well matched energy level arrangement and bipolar transport ability of the emitters which facilitate effective carrier injection, transport and recombination. The maximum luminance, current efficiency, power efficiency and EQE of 7844 cd cm $^{-2}$ , 1.52 cd A $^{-1}$ , 1.35 lm  $W^{-1}$  and 7.67% are achieved simultaneously in the device N1.

In particular, the EQE of device N1 remains extraordinarily high at 7.65% even at a high luminance of 3300 cd  $m^{-2}$ , demonstrating negligible efficiency roll-off. This can be attributed to the rapid  $k_r$  value and balanced bipolar property of 3,6-mPPICNC3. Meanwhile, devices N2–4 achieve the maximum EQE values of 6.16%, 5.39%, and 6.35%, and maintain EQE levels of 5.56%, 5.23% and 6.05% at 1000 cd m<sup>-2</sup>, respectively. The EL performance of device N3 based on 2,7-mPPICNC3 is unsatisfactory compared to the other devices. This can be attributed to its long fluorescence lifetime and imbalanced hole/electron mobilities. Here, we define  $J_{90}$ as the current density at which the EQE falls to 90% of its peak value, as a means of assessing efficiency roll-off. In this context, a high  $J_{90}$  value indicates a low efficiency roll-off. The  $J_{90}$ s of non-doped devices N1–4 can be extracted to be 327, 41, 486, and 31 mA cm−<sup>2</sup> , respectively. Such superior values achieved in the devices N1 and N3 with 3,6-pPPICNC3 and 2,7 mPPICNC3 as emitters surpass those of most traditional fluorescent OLEDs.<sup>29</sup>

The EUE of OLEDs can be described by eqn (4):

$$
EUE = \frac{EQE}{\gamma \times \Phi_{PL} \times \eta_{OUT}} \tag{4}
$$

Here,  $\gamma$  is the recombination efficiency of the injected holes and electrons (ideally 100%),  $\eta_{\text{OUT}}$  is the light out coupling efficiency



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(usually estimated to be 20-30%),  $\Phi_{PL}$  is the PLQY of the neat film (59.1% for 3,6-mPPICNC3, 63.0% for 3,6-pPPICNC3, 61.9% for 2,7-mPPICNC3 and 63.3% for 2,7-pPPICNC3). The corresponding EUEs are calculated to be 43.3–64.9%, 32.6–48.9%, 29.0–43.5% and 33.4–50.2% for devices N1–4, respectively, which break through the upper limit of 25% in conventional fluorescent OLEDs. The large  $\Delta E_{\text{S,T}_1}$  and single-exponential decay lifetime in the nanosecond range of four emitters can rule out the TADF mechanism. Meanwhile, the luminance and current densities of the devices exhibit a good linear relationship (Fig. S19†), confirming that triplet–triplet annihilation (TTA) up-conversion is not the utilization channel of triplet excitons. Combining the analysis of the photophysical properties and theoretical calculations, the HLCT mechanism should be the main reason for their excellent EL efficiencies.

In order to reduce the adverse effects of aggregation, the doped devices $(D1-4)$  using  $4,4'-bis(N-carbazolyl)-1,1'-biphenyl$ (CBP) as a host for 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7 mPPICNC3 and 2,7-pPPICNC3 were prepared with the doping concentration of 5 wt%. As shown in Fig. 7a, b, S20 and S21,† compared to the non-doped OLEDs, devices D1–4 show obvious blue shifts with emission wavelengths of 391-426 nm and narrow FWHM values, corresponding to the CIE coordinates of (0.161, 0.025), (0.160, 0.035), (0.161, 0.033), and (0.156, 0.063), respectively. Notably, the maximum EQEs of doped devices are improved to be 7.85%, 7.51%, 5.52% and 6.47%. It is especially noteworthy that the 3,6-mPPICNC3-based device D1 not only shows stable NUV light with perfect color purity but also achieves a high EQE and minimal efficiency roll-off, maintaining an EQE value of 7.48% at 1000 cd m<sup>-2</sup>. The  $J_{90}$  value of device D1 can be extracted to be 224 mA  $cm^{-2}$ .

Until now, though the record-high EQE of 11.3% has been achieved in doped HLCT-based OLEDs with a CIEy value of less than  $0.05$ , $31$  most reported devices have exhibited low brightness, serious efficiency roll-off or poor color purity, resulting from unbalanced exciton recombination, exciton quenching effects, strong intramolecular CT state, and aggregation effect, especially in non-doped OLEDs. To the best of our knowledge, 3,6-mPPICNC3-based non-doped device N1 achieves an EQE of 7.67% with negligible efficiency roll-off up to a luminance of 3300 cd  $m^{-2}$ , which sets a new record among the non-doped NUV-OLEDs with a CIEy value of less than 0.05 (Fig. 7c, and Table S11†). In addition, the doped device D1 shows an EQE of 7.48% at 1000 cd m−<sup>2</sup> and a narrow FWHM of 41 nm with an emission peak smaller than 400 nm, outperforming most reported doped OLEDs (Fig. 7d, and Table S10†). It is worth emphasizing that our work not only provides an effective design strategy to alleviate the contradictions among the wide-bandgap emission, fluorescence efficiency and aggregation effect, but also realizes balanced bipolar transport and low efficiency rolloff at high brightness through the approach of molecular configuration engineering. In order to further improve the EL efficiencies, it is essential to suppress the competitive intersystem crossing (IC) process from high-lying triplet states to the  $T_1$  state by introducing functional groups (such as anthracene) with a low  $T_1$  energy level.



Fig. 7 (a) Normalized EL spectra at different applied voltages of the devices D1 and D2. (b) EQE versus luminance curves of the devices D1-4. EQEmax versus CIEy of the reported non-doped (c) and doped (d) HLCT-based OLEDs with a CIEy value below 0.05.

### Conclusion

In summary, four efficient wide-bandgap HLCT emitters, namely 3,6-mPPICNC3, 3,6-pPPICNC3, 2,7-mPPICNC3 and 2**,7-pPPICNC3,** featuring a unique D′–D–A structure, have been successfully designed and synthesized. It is found that such novel structure endows the emitters with a PLICT character, resulting in high PLQYs in both the solution and neat film. On the other hand, high and balanced bipolar transport was achieved by molecular configuration engineering. As a result, the OLED employing 3,6-mPPICNC3 as an emitter not only achieves stable NUV emission with CIE color coordinates of (0.160, 0.032) and a narrow FWHM of 44 nm, but also exhibits a record-breaking EQE of 7.67% and negligible efficiency rolloff as the luminance increases to 3300 cd m−<sup>2</sup> in the nondoped device. Furthermore, remarkable EL performance, including an emission peak at 391 nm, a narrow FWHM of 41 nm and a maximum EQE of 7.85%, is achieved simultaneously in the doped device. This work reveals that the D′–D–A type molecular design is a feasible and potentially promising approach to developing efficient and balanced bipolar widebandgap emitters and achieving high-performance NUV-OLEDs with high efficiency, low efficiency roll-off, and good color purity.

## Data availability

All data supporting the findings of this study are presented in the article and ESI.† Additional data are available from the corresponding author upon reasonable request.

### Author contributions

H. Qi, Z. Gao, and S. Wang conducted the synthesis, basic properties characterizations, and theoretical calculations. D. Xie, D. Ma, and S. Ying performed the fabrications and characterization studies of the devices. H. Qi, L. Peng, and Y. Liu, contributed to writing the manuscript, and all the authors revised it. S. Ying, D. Ma, and S. Yan conceived the idea, and supervised this study.

## Conflicts of interest

The authors declare that they have no known competing nancial interests or personal relationships that could have appeared to influence the work reported in this paper.

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## Notes and references

- 1 Y. Luo, S. Li, Y. Zhao, C. Li, Z. Pang, Y. Huang, M. Yang, L. Zhou, X. Zheng, X. Pu and Z. Lu, Adv. Mater., 2020, 32, 2001248.
- 2 C. Du, H. Liu, Z. Cheng, S. Zhang, Z. Qu, D. Yang, X. Qiao, Z. Zhao and P. Lu, Adv. Funct. Mater., 2023, 33, 2304854.
- 3 M. Xie, Y. Zhou, H. Zhou, C. Ma, Q. Sun, S.-T. Zhang, Y. Zhang, W. Yang and S. Xue, Chem. Sci., 2024, 15, 5589– 5595.
- 4 S. Wang, L. Peng, F. He, Y. Ming, H. Qi, Y. Liu, D. Ma, S. Ying and S. Yan, Adv. Opt. Mater., 2024, 2024, 2400503.
- 5 A. Salehi, X. Fu, D. H. Shin and F. So, Adv. Funct. Mater., 2019, 29, 1808803.
- 6 M. Du, M. Mai, D. Zhang, L. Duan and Y. Zhang, Chem. Sci., 2024, 15, 3148–3154.
- 7 J. Xu, H. Liu, J. Li, Z. Zhao and B. Z. Tang, Adv. Opt. Mater., 2021, 9, 2001840.
- 8 J. Wang, Y. Yang, C. Jiang, M. He, C. Yao and J. Zhang, J. Mater. Chem. C, 2022, 10, 3163–3171.
- 9 X. Guo, P. Yuan, X. Qiao, D. Yang, Y. Dai, Q. Sun, A. Qin, B. Z. Tang and D. Ma, Adv. Funct. Mater., 2020, 30, 1908704.
- 10 S. Chen, P. Zeng, W. Wang, X. Wang, Y. Wu, P. Lin and Z. Peng, J. Mater. Chem. C, 2019, 7, 2886–2897.
- 11 T. C. Chao, Y. T. Lin, C. Y. Yang, T. S. Hung, H. C. Chou, C. C. Wu and K. T. Wong, Adv. Mater., 2005, 17, 992–996.
- 12 J. Shinar and R. Shinar, J. Phys. D: Appl. Phys., 2008, 41, 133001.
- 13 J. Bian, S. Chen, L. Qiu, N. Zhang, J. Zhang, C. Duan, C. Han and H. Xu, Research, 2022, 2022, 9838120.
- 14 X. Guo, G. Li, J. Lou, K. Chen, R. Huang, D. Yang, H. Zhang, Z. Wang and B. Z. Tang, Small, 2022, 18, 2204029.
- 15 S. Zeng, C. Xiao, J. Zhou, Q. Dong, Q. Li, J. Lim, H. Ma, J. Y. Lee, W. Zhu and Y. Wang, Adv. Funct. Mater., 2022, 32, 2113183.
- 16 H. Liu, Q. Bai, L. Yao, H. Zhang, H. Xu, S. Zhang, W. Li, Y. Gao, J. Li, P. Lu, H. Wang, B. Yang and Y. Ma, Chem. Sci., 2015, 6, 3797–3804.
- 17 Y. Huo, J. Lv, M. Wang, Z. Duan, H. Qi, S. Wang, Y. Liu, L. Peng, S. Ying and S. Yan, J. Mater. Chem. C, 2023, 11, 6347–6353.
- 18 Z. Zhong, X. Zhu, X. Wang, Y. Zheng, S. Geng, Z. Zhou, X. J. Feng, Z. Zhao and H. Lu, Adv. Funct. Mater., 2022, 32, 2112969.
- 19 S. S. Tang, G. X. Yang, J. J. Zhu, X. He, J. X. Jian, F. Lu and Q. X. Tong, Chem.–Eur. J., 2021, 27, 9102–9111.
- 20 P. Han, A. Qin and B. Z. Tang, Chem. Res. Chin. Univ., 2021, 37, 16–24.
- 21 H. Zhang, G. Li, X. Guo, K. Zhang, B. Zhang, X. Guo, Y. Li, J. Fan, Z. Wang, D. Ma and B. Z. Tang, Angew. Chem., Int. Ed., 2021, 60, 22241–22247.
- 22 T. Chen, J. Lou, H. Wu, J. Luo, D. Yang, X. Qiao, H. Zhang, B. Z. Tang and Z. Wang, Adv. Opt. Mater., 2023, 11, 2301053.
- 23 G. Li, B. Li, H. Zhang, X. Guo, C. Lin, K. Chen, Z. Wang, D. Ma and B. Z. Tang, ACS Appl. Mater. Interfaces, 2022, 14, 10627–10636.
- 24 L. Peng, Y. Huo, L. Hua, J. Lv, Y. Liu, S. Ying and S. Yan, J. Mater. Chem. C, 2022, 10, 9621–9627.
- 25 Y. Zheng, X. Zhu, Z. Ni, X. Wang, Z. Zhong, X. J. Feng, Z. Zhao and H. Lu, Adv. Opt. Mater., 2021, 9, 2100965.
- 26 X. Q. Gan, Z. M. Ding, D. H. Liu, W. Q. Zheng, B. Ma, H. Zhang, X. Chang, L. Wang, Y. Liu, X. Wu, S. J. Su and W. Zhu, Adv. Opt. Mater., 2023, 11, 2300195.
- 27 S. Geng, Z. Liu, H. Li, Z. Zhong, X. J. Feng, Z. Zhao and H. Lu, Adv. Opt. Mater., 2023, 12, 2301344.
- 28 C. Brouillac, W.-S. Shen, J. Rault-Berthelot, O. Jeannin, C. Quinton, Z.-Q. Jiang and C. Poriel, Mater. Chem. Front., 2022, 6, 1803–1813.
- 29 P. Ma, Y. Chen, Y. Man, Q. Qi, Y. Guo, H. Wang, Z. Li, P. Chang, C. Qu, C. Han and H. Xu, Angew. Chem., Int. Ed., 2023, 63, e202316479.
- 30 Y. Xu, P. Xu, D. Hu and Y. Ma, Chem. Soc. Rev., 2021, 50, 1030–1069.
- 31 G. Li, K. Xu, J. Zheng, X. Fang, W. Lou, F. Zhan, C. Deng, Y.-F. Yang, Q. Zhang and Y. She, J. Am. Chem. Soc., 2024, 146, 1667–1680.
- 32 H. Zhang, G. Li, X. Guo, K. Zhang, B. Zhang, X. Guo, Y. Li, J. Fan, Z. Wang, D. Ma and B. Z. Tang, Angew. Chem., Int. Ed., 2021, 60, 22241–22247.
- 33 J. Chen, H. Liu, J. Guo, J. Wang, N. Qiu, S. Xiao, J. Chi, D. Yang, D. Ma, Z. Zhao and B. Z. Tang, Angew. Chem., Int. Ed., 2022, 61, e202116810.
- 34 L. Peng, J. Lv, S. Xiao, Y. Huo, Y. Liu, D. Ma, S. Ying and S. Yan, Chem. Eng. J., 2022, 450, 138339.
- 35 P. Han, C. Lin, D. Ma, A. Qin and B. Z. Tang, ACS Appl. Mater. Interfaces, 2020, 12, 46366–46372.
- 36 A. Obolda, Q. Peng, C. He, T. Zhang, J. Ren, H. Ma, Z. Shuai and F. Li, Adv. Mater., 2016, 28, 4740–4746.
- 37 S. Y. Chang, G. T. Lin, Y. C. Cheng, J. J. Huang, C. L. Chang, C. F. Lin, J. H. Lee, T. L. Chiu and M. K. Leung, ACS Appl. Mater. Interfaces, 2018, 10, 42723–42732.
- 38 H. Lim, H. J. Cheon, S. J. Woo, S. K. Kwon, Y. H. Kim and J. J. Kim, Adv. Mater., 2020, 32, e2004083.
- 39 M. Chen, Y. Yuan, J. Zheng, W.-C. Chen, L.-J. Shi, Z.-L. Zhu, F. Lu, Q.-X. Tong, Q.-D. Yang, J. Ye, M.-Y. Chan and C.-S. Lee, Adv. Opt. Mater., 2015, 3, 1215–1219.
- 40 C. Li, J. Wei, J. Han, Z. Li, X. Song, Z. Zhang, J. Zhang and Y. Wang, J. Mater. Chem. C, 2016, 4, 10120–10129.
- 41 H. Wei, R. Zhang, G. Huang, Y. Yuan and W. Chen, Opt. Mater., 2022, 128, 112345.
- 42 C. Liao, B. Chen, Q. Xie, X. Li, H. Liu and S. Wang, Adv. Mater., 2023, 35, 2305310.

- 43 Y. Huo, J. Lv, Y. Xie, L. Hua, Y. Liu, Z. Ren, T. Li, S. Ying and S. Yan, ACS Appl. Mater. Interfaces, 2022, 14, 57092–57101.
- 44 Y. Huo, H. Qi, S. He, J. Li, S. Song, J. Lv, Y. Liu, L. Peng, S. Ying and S. Yan, Aggregate, 2023, 4, e391.
- 45 J. Ye, Z. Chen, M.-K. Fung, C. Zheng, X. Ou, X. Zhang, Y. Yuan and C.-S. Lee, Chem. Mater., 2013, 25, 2630–2637.
- 46 X. Yang, S. Zheng, R. Bottger, H. S. Chae, T. Tanaka, S. Li, A. Mochizuki and G. E. Jabbour, J. Phys. Chem. C, 2011, 115, 14347–14352.
- 47 L. Peng, J. Lv, Y. Huo, L. Hua, Y. Liu, S. Ying and S. Yan, Dyes Pigm., 2022, 206, 110676.
- 48 B. Wex and B. R. Kaafarani, J. Mater. Chem. C, 2017, 5, 8622.
- 49 Z. Wang, T. Yang, S. Dong, Z. Wen, H. Xu, Y. Miao, H. Wang and J. Yu, Dyes Pigm., 2022, 199, 110047.
- 50 R. Ma, Z. Ma, X. Wang, Z. Si, Q. Duan and S. Shao, Chem. Eng. J., 2022, 447, 137517.
- 51 S. K. Shin, S. Y. Byeon, S. H. Han and J. Y. Lee, Adv. Opt. Mater., 2018, 6, 1701007.
- 52 R. K. Konidena, K. R. J. Thomas, A. Pathak, D. K. Dubey, S. Sahoo and J.-H. Jou, ACS Appl. Mater. Interfaces, 2018, 10, 24013–24027.
- 53 H. Uoyama, K. Goushi, K. Shizu, H. Nomura and C. Adachi, Nature, 2012, 492, 234–238.
- 54 S. Zhang, L. Yao, Q. Peng, W. Li, Y. Pan, R. Xiao, Y. Gao, C. Gu, Z. Wang, P. Lu, F. Li, S. Su, B. Yang and Y. Ma, Adv. Funct. Mater., 2015, 25, 1755–1762.
- 55 S. Ying, W. Liu, L. Peng, Y. Dai, D. Yang, X. Qiao, J. Chen, L. Wang and D. Ma, Adv. Opt. Mater., 2022, 10, 2101920.
- 56 R. Guo, W. Liu, S. Ying, Y. Xu, Y. Wen, Y. Wang, D. Hu, X. Qiao, B. Yang, D. Ma and L. Wang, Sci. Bull., 2021, 66, 2090–2098.
- 57 X. Tang, Q. Bai, T. Shan, J. Li, Y. Gao, F. Liu, H. Liu, Q. Peng, B. Yang, F. Li and P. Lu, Adv. Funct. Mater., 2018, 28, 1705813.
- 58 Y. Xu, X. Liang, X. Zhou, P. Yuan, J. Zhou, C. Wang, B. Li, D. Hu, X. Qiao, X. Jiang, L. Liu, S.-J. Su, D. Ma and Y. Ma, Adv. Mater., 2019, 31, 1807388.
- 59 G.-X. Yang, H.-J. Tan, J.-W. Zhao, J.-J. Zhu, X. He, J.-X. Jian, M.-H. Zhou, S.-L. Tao and Q.-X. Tong, Chem. Eng. J., 2022, 445, 136813.
- 60 F. Liu, G. Cao, Z. Feng, Z. Cheng, Y. Yan, Y. Xu, Y. Jiang, Y. Chang, Y. Lv and P. Lu, ACS Appl. Mater. Interfaces, 2023, 15, 47307–47316.
- 61 G. Haberhauer, R. Gleiter and C. Burkhart, Chem.–Eur. J., 2015, 22, 971–978.
- 62 G. Haberhauer, Chem.–Eur. J., 2017, 23, 9288–9296.
- 63 H. Wu, L. Du, J. Luo, Z. Wang, D. L. Phillips, A. Qin and B. Z. Tang, J. Mater. Chem. C, 2022, 10, 8174–8180.
- 64 R. Ahmed and A. K. Manna, J. Phys. Chem. A, 2022, 126, 4221– 4229.
- 65 M. A. El-Sayed, J. Chem. Phys., 1963, 38, 2834–2838.
- 66 M. K. Etherington, J. Gibson, H. F. Higginbotham, T. J. Penfold and A. P. Monkman, Nat. Commun., 2016, 7, 13680.
- 67 Z. Gao, Z. Wang, T. Shan, Y. Liu, F. Shen, Y. Pan, H. Zhang, X. He, P. Lu, B. Yang and Y. Ma, Org. Electron., 2014, 15, 2667–2676. Chemical Science Companies Article. Published on 14 June 2024. Downloaded on 14 June 2024. The Solidary Article is licensed under a strained on the strained on 14 June 2024. The Solidary Commons Articles. The Solidary Com
	- 68 J. Lou, G. Li, X. Guo, B. Li, D. Yang, H. Zhang, Z. Wang and B. Z. Tang, Small, 2023, 202308468.
	- 69 B. Li, J. Lou, H. Zhang, G. Li, X. He, Y. Huang, N. Zheng, Z. Wang, D. Ma and B. Z. Tang, Adv. Funct. Mater., 2023, 33, 2212876.
	- 70 Y. Liu, X. Man, Q. Bai, H. Liu, P. Liu, Y. Fu, D. Hu, P. Lu and Y. Ma, CCS Chem., 2022, 4, 214–227.
	- 71 W. Wang, K. Chen, H. Wu, Y. Long, J. Zhao, L. Jiang, S. Liu, Z. Chi, J. Xu and Y. Zhang, ACS Appl. Mater. Interfaces, 2023, 15, 13415–13426.
	- 72 H. Xu, P. Sun, K. Wang, J. Li, F. Wang, Y. Miao, H. Wang, B. Xu and W.-Y. Wong, J. Mater. Chem. C, 2017, 5, 4455–4462.
	- 73 M. Sun, C. Ma, M. Xie, L. Chu, Q. Sun, W. Yang and S. Xue, Chem. Eng. J., 2024, 480, 148107.
	- 74 J. Lv, S. Song, J. Li, L. Peng, Y. Li, Y. Liu, D. Ma, S. Ying and S. Yan, Adv. Opt. Mater., 2023, 12, 2301413.